

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

2SC2555

SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS.

HIGH SPEED DC-DC CONVERTER APPLICATIONS.

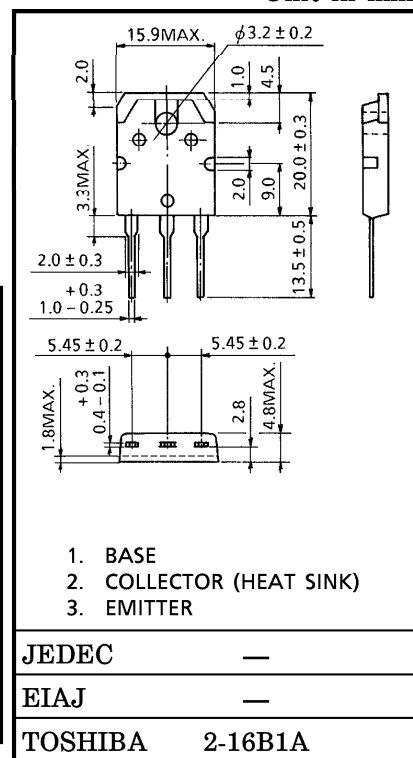
- Excellent Switching Times
: $t_r = 1.0\mu s$ (Max.), $t_f = 1.0\mu s$ (Max.) at $I_C = 4A$
- High Collector Breakdown Voltage : $V_{CEO} = 400V$

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	500	V
Collector-Emitter Voltage		V_{CEO}	400	V
Emitter-Base Voltage		V_{EBO}	7	V
Collector Current	DC	I_C	8	A
	Pulse	I_{CP}	10	A
Base Current		I_B	4	A
Collector Power Dissipation	$T_a = 25^\circ C$	P_C	2.5	W
	$T_c = 25^\circ C$		80	
Junction Temperature		T_j	150	$^\circ C$
Storage Temperature Range		T_{stg}	-55~150	$^\circ C$

INDUSTRIAL APPLICATIONS

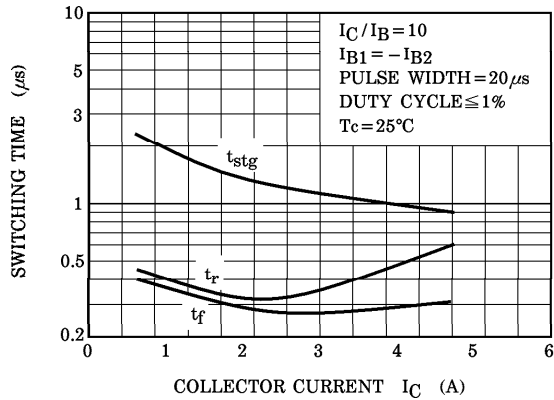
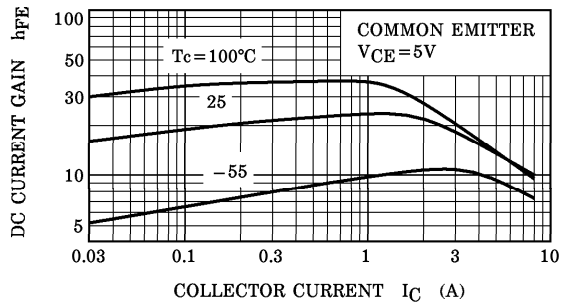
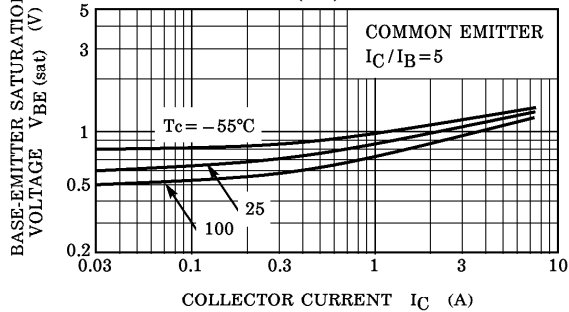
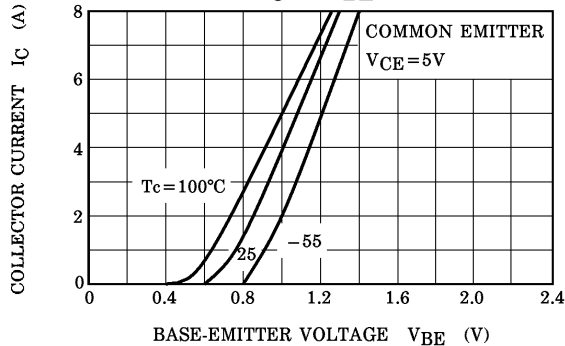
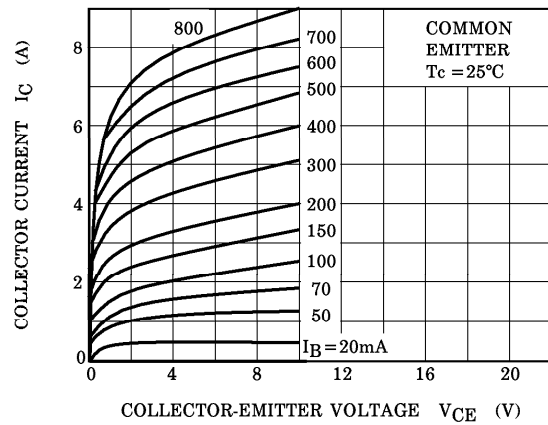
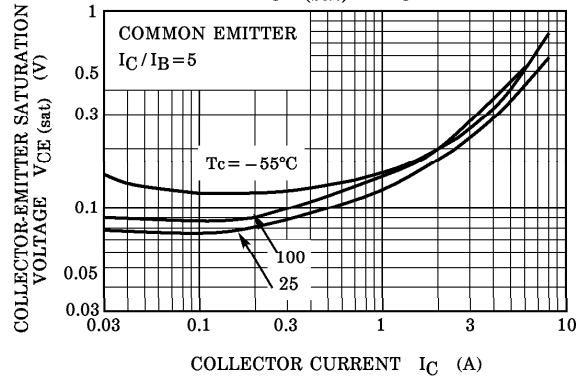
Unit in mm

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

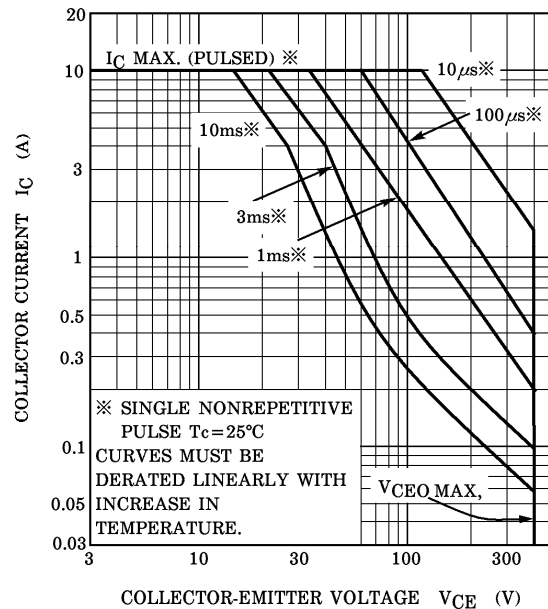
Weight : 4.6g

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB} = 400V, I_E = 0$	—	—	100	μA
Emitter Cut-off Current		I_{EBO}	$V_{EB} = 7V, I_C = 0$	—	—	1	mA
Collector-Base Breakdown Voltage		$V_{(BR)CBO}$	$I_C = 1mA, I_E = 0$	500	—	—	V
Collector-Emitter Breakdown Voltage		$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	400	—	—	V
DC Current Gain		$h_{FE(1)}$	$V_{CE} = 5V, I_C = 1A$	15	—	—	
		$h_{FE(2)}$	$V_{CE} = 5V, I_C = 4A$	10	—	—	
Saturation Voltage	Collector-Emitter	$V_{CE(sat)}$	$I_C = 4A, I_B = 0.8A$	—	—	1.0	V
	Base-Emitter	$V_{BE(sat)}$	$I_C = 4A, I_B = 0.8A$	—	—	1.5	
Switching Time	Rise Time	t_r		—	—	1.0	μs
	Storage Time	t_{stg}		—	—	2.5	
	Fall Time	t_f		—	—	1.0	

SWITCHING CHARACTERISTICS

 $h_{FE} - I_C$  $V_{BE(sat)} - I_C$  $I_C - V_{BE}$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$ 

SAFE OPERATING AREA



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